

BAP70AM

Silicon PIN diode array Rev. 01 — 20 November 2006

Product data sheet

Product profile

1.1 General description

Four planar PIN diode array in SOT363 small SMD plastic package.

1.2 Features

- High voltage current controlled RF resistor for RF attenuators
- Low diode capacitance
- Very low series inductance
- Low distortion

1.3 Applications

- RF attenuators
- (SAT) TV applications
- Car radio applications

Pinning information 2.

Table 1. **Discrete pinning**

Pin	Description	Simplified outline	Symbol		
1	anode diode 1	D- D- D-			
2	cathode diode 2	6 5 4	6 5 4		
3	anode diode 3 / cathode diode 4				
4	anode diode 4	0			
5	cathode diode 3	□1 □2 □3	1 2 3 sym118		
6	anode diode 2 / cathode diode 1				

Ordering information 3.

Table 2. **Ordering information**

Type number	Package		
	Name	Description	Version
BAP70AM	-	plastic surface-mounted package; 6 leads	SOT363



Silicon PIN diode array

4. Marking

Table 3. Marking

Type number	Marking code
BAP70AM	N9

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_R	reverse voltage		-	50	V
I _F	forward current		-	100	mA
P _{tot}	total power dissipation	$T_{sp} = 90 ^{\circ}C$	-	300	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-65	+150	°C

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point		260	K/W

7. Characteristics

Table 6. Characteristics

 $T_{amb} = 25 \,^{\circ}C$ unless otherwise specified.

	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 50 \text{ mA}$	-	0.9	1.1	V
I _R	reverse current	V _R = 50 V	-	-	<100	nA
C _d	diode capacitance	see Figure 1; f = 1 MHz;	-			
		$V_R = 0 V$	-	570	-	fF
		V _R = 1 V	-	400	-	fF
		V _R = 5 V	-	270	-	fF
		V _R = 20 V	-	200	250	fF
r _D	diode forward resistance	see Figure 2; f = 100 MHz;	-			
		I _F = 0.5 mA	-	77	100	Ω
		I _F = 1 mA	-	40	50	Ω
		I _F = 10 mA	-	5.4	7	Ω
		I _F = 100 mA	-	1.4	1.9	Ω
$ au_{L}$	charge carrier life time	when switched from I $_{F}$ = 10 mA to I $_{R}$ = 6 mA; R $_{L}$ = 100 $\Omega;$ measured at I $_{R}$ = 3 mA	-	1.25	-	μs
Ls	series inductance	$I_F = 100 \text{ mA}$; $f = 100 \text{ MHz}$	-	0.6	-	nΗ

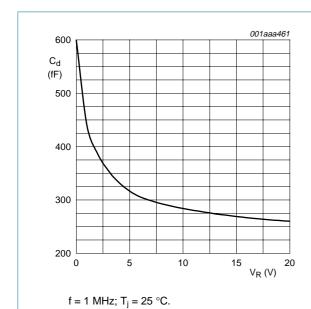
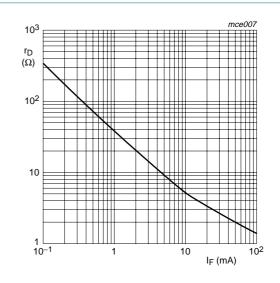


Fig 1. Diode capacitance as a function of reverse voltage; typical values



f = 100 MHz; $T_i = 25 \,^{\circ}\text{C}$.

Fig 2. Diode forward resistance as a function of forward current; typical values

Package outline

Plastic surface-mounted package; 6 leads

SOT363

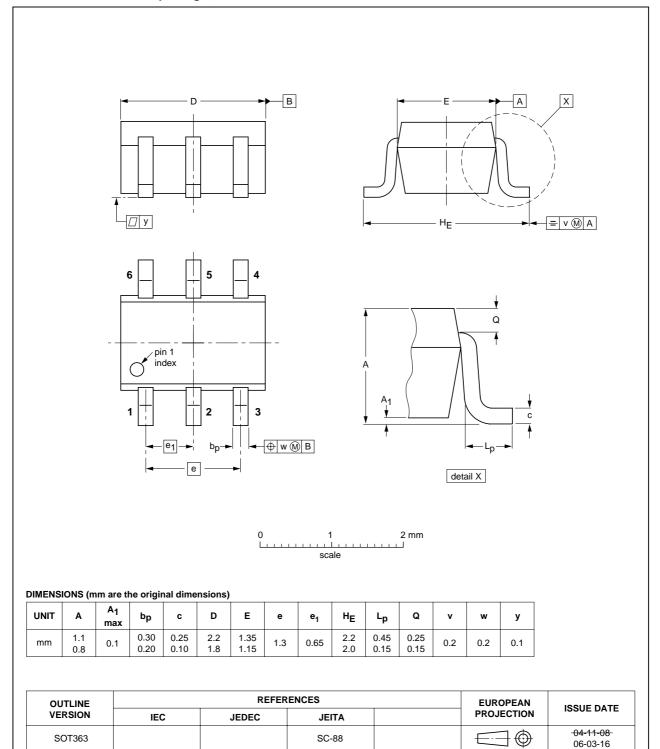


Fig 3. Package outline SOT363



Silicon PIN diode array

9. Abbreviations

Table 7. Abbreviations

Acronym	Description
PIN	P-type, Intrinsic, N-type
SMD	Surface Mounted Device
RF	Radio Frequency
SAT	Satellite

10. Revision history

Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BAP70AM_1	20061120	Product data sheet	-	-

Silicon PIN diode array

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

11.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

11.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or

malfunction of a NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

11.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

12. Contact information

For additional information, please visit: http://www.nxp.com

For sales office addresses, send an email to: salesaddresses@nxp.com

BAP70AM_1 © NXP B.V. 2006. All rights reserved.

BAP70AM

Silicon PIN diode array

13. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications
2	Pinning information 1
3	Ordering information
4	Marking 2
5	Limiting values
6	Thermal characteristics
7	Characteristics
8	Package outline 4
9	Abbreviations 5
10	Revision history 5
11	Legal information 6
11.1	Data sheet status 6
11.2	Definitions
11.3	Disclaimers 6
11.4	Trademarks
12	Contact information 6
13	Contents 7

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.





© NXP B.V. 2006.

All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 20 November 2006

Document identifier: BAP70AM_1